

www.vishay.com

Vishay Semiconductors

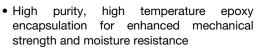
High Performance Schottky Rectifier, 2 x 10 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 10 A							
V_{R}	80 V, 90 V, 100 V							
V _F at I _F	0.70 V							
I _{RM} max.	6 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	24 mJ							
Package	3L TO-220AB							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform (per device)	20	Α					
I _{FRM}	T _C = 133 °C per leg	20	Α					
V _{RRM}		80/100	V					
I _{FSM}	t _p = 5 μs sine	850	Α					
V_{F}	10 A _{pk} , T _J = 125 °C	0.70	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL MBR2080CT-M3 MBR2090CT-M3 MBR20100CT-M3 UNITS								
Maximum DC reverse voltage	V_R	80	90	100	W			
Maximum working peak reverse voltage	V_{RWM}	00	90	100	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average per leg			T 100 °C reted V		10			
forward current	per device	$I_{F(AV)}$ $T_C = 133 ^{\circ}\text{C}$, rated V_R		20				
Peak repetitive forward current per leg		I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 133 °C		20			
Non-repetitive peak surge current		I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	850	А		
			Surge applied at rated load conditions halfwave, single phase, 60 Hz		150			
Peak repetitive reverse sur	ge current	I _{RRM}	2.0 μs, 1.0 kHz	0.5				
Non-repetitive avalanche energy per leg			T _J = 25 °C, I _{AS} = 2 A, L = 12	mH	24	mJ		

Revision: 18-Aug-17 1 Document Number: 96282



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS					
		10 A	T _{.1} = 25 °C	0.80	V			
Maximum forward voltage drap	V _{FM} ⁽¹⁾	20 A	1j=25 C	0.95				
Maximum forward voltage drop	V _{FM} (··)	10 A	T 105 °C	0.70				
		20 A	T _J = 125 °C	0.85				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.10	mΛ			
Maximum instantaneous reverse current		T _J = 125 °C	Rated DC voltage	6	mA			
Threshold voltage	V _{F(TO)}	T T manyimum		0.433	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum		15.8	mΩ			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal rang	400	pF				
Typical series inductance	L _S	Measured from top of termi	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

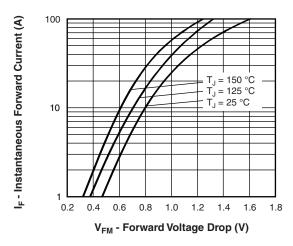
Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temper	erature range	TJ		-65 to +150	°C			
Maximum storage tempe	rature range	T _{Stg}		-65 to +175				
Maximum thermal resista junction to case per leg	ance,	R _{thJC}	DC operation	2.0				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	°C/W			
Maximum thermal resistance, junction to ambient		R _{thJA}	DC operation (For D ² PAK and TO-262)	50				
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	g torque minimum maximum			6 (5)	kg∙ cm			
woulding torque				12 (10)	(lbf·in)			
Marking device			Case style 3L TO-220AB	MBR2 MBR2 MBR20	090CT			

www.vishay.com

Vishay Semiconductors



100 I_R - Reverse Current (mA) 10 T₁ = 125 °C 0.1 0.01 0.001 $T_1 = 25 \, ^{\circ}C$ 0.0001 0 20 40 60 80 100 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

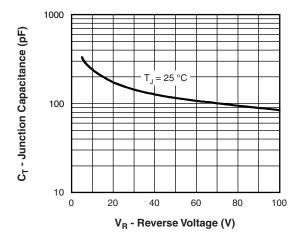


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

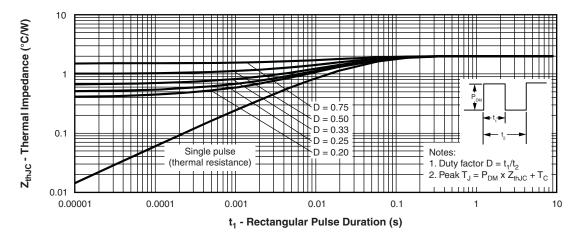


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

www.vishay.com

Vishay Semiconductors

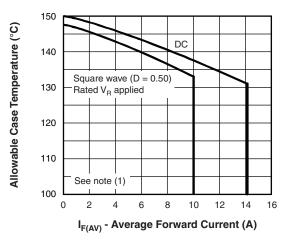


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

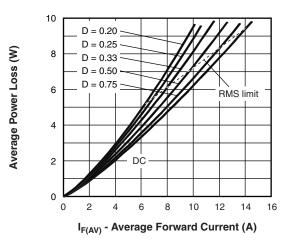


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

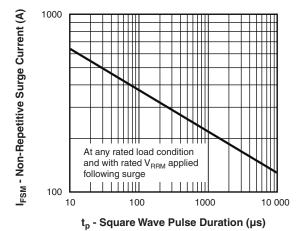


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

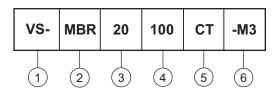
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

- Schottky MBR series

- Current rating (20 = 20 A)

080 = 80 V

Voltage ratings

090 = 90 V

T OT ----

100 = 100 V

5

CT = essential part numberEnvironmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-MBR2080CT-M3	50	1000	Antistatic plastic tube							
VS-MBR2090CT-M3	50	1000	Antistatic plastic tube							
VS-MBR20100CT-M3	50	1000	Antistatic plastic tube							

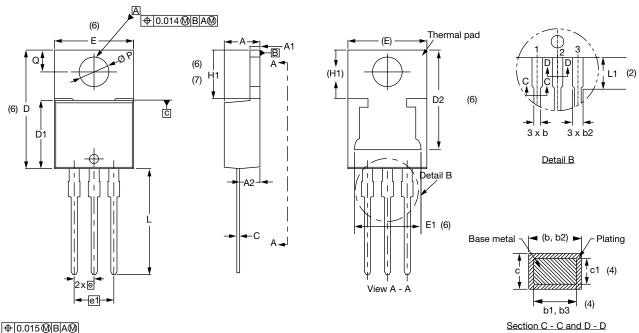
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96154</u>						
Part marking information	www.vishay.com/doc?95028					

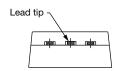


Vishay Semiconductors

3L TO-220AB

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6, 7
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355			·					

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2 (minimum)



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.